

Form PTO-1449		Docket Number (Optional) HT-02-026		Application Number 10/647,718		
INFORMATION DISCLOSURE CITATION IN AN APPLICATION  (Use several sheets if necessary)		Applicant Yimin Guo				
		Filing Date 08/25/03		Group Art Unit		
U. S. PATENT DOCUMENTS						
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILED DATE IF APPROPRIATE
PC	6358757	3/19/02	Anthony	438	3	4/3/01
PC	6413788	7/2/02	Tuttle	438	3	2/28/01
PC	6417561	7/9/02	Tuttle	257	659	7/27/01
FOREIGN PATENT DOCUMENTS						
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation YES NO
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)						
PC	U.S. Patent Application Publication US 2002/0055190 A1 to Anthony, "Magnetic Memory with Structures that Prevent Disruptions to Magnetization in Sense Layer", Pub Date 5/9/02, US Class 438/3.					
EXAMINER			DATE CONSIDERED			
PHAT X. CAO			11/12/04			
EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.						

